

## ADCS7476 ADCS7477

## ADCS7478 1MSPS, 12-/10-/8-Bit A/D Converters in SOT-23 & WSON

Check for Samples: ADCS7476, ADCS7477, ADCS7478

#### **FEATURES**

- Variable Power Management
- Packaged in 6-Lead, SOT-23 and WSON
- Power Supply used as Reference
- Single +2.7V to +5.25V Supply Operation
- SPI™/QSPI™/MICROWIRE™/DSP Compatible

#### **APPLICATIONS**

- Automotive Navigation
- FA/ATM Equipment
- Portable Systems
- Medical Instruments
- Mobile Communications
- Instrumentation and Control Systems

#### **KEY SPECIFICATIONS**

- Resolution with no Missing Codes 12/10/8 bits
- Conversion Rate 1 MSPS
- DNL +0.5, -0.3 LSB (typ)
- INL ± 0.4 LSB (typ)
- Power Consumption
  - 3V Supply 2 mW (typ)
  - 5V Supply 10 mW (typ)

#### DESCRIPTION

The ADCS7476, ADCS7477, and ADCS7478 are low power, monolithic CMOS 12-, 10- and 8-bit analog-to-digital converters that operate at 1 MSPS. The ADCS7476/77/78 are drop-in replacements for Analog Devices' AD7476/77/78. Each device is based on a successive approximation register architecture with internal track-and-hold. The serial interface is compatible with several standards, such as SPI™, QSPI™, MICROWIRE™, and many common DSP serial interfaces.

The ADCS7476/77/78 uses the supply voltage as a reference, enabling the devices to operate with a fullscale input range of 0 to  $V_{\text{DD}}$ . The conversion rate is determined from the serial clock (SCLK) speed. These converters offer a shutdown mode, which can be used to trade throughput for power consumption. The ADCS7476/77/78 is operated with a single supply that can range from +2.7V to +5.25V. Normal power consumption during continuous conversion, using a +3V or +5V supply, is 2 mW or 10 mW respectively. The power down feature, which is enabled by a chip select (CS) pin, reduces the power consumption to under 5 µW using a +5V supply. All three converters are available in a 6-lead, SOT-23 package and in a 6-lead WSON, both of which provide an extremely small footprint for applications where space is a critical consideration. These products are designed for operation over the automotive/extended industrial temperature range of -40°C to +125°C.

#### **Connection Diagram**

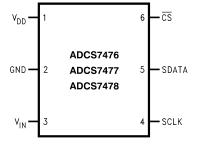


Figure 1. 6-Lead SOT-23 or WSON See DBV or NGF Package

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

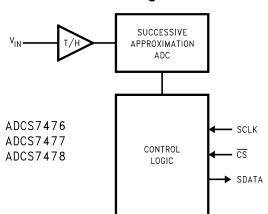
All trademarks are the property of their respective owners.



#### PIN DESCRIPTIONS

Pin No.	Symbol	Description
FIII NO.	Syllibol	Description
ANALOG I/O		
3	V <sub>IN</sub>	Analog input. This signal can range from 0V to V <sub>DD</sub> .
DIGITAL I/O		
4	SCLK	Digital clock input. The range of frequencies for this input is 10 kHz to 20 MHz, with ensured performance at 20 MHz. This clock directly controls the conversion and readout processes.
5	SDATA	Digital data output. The output words are clocked out of this pin by the SCLK pin.
6	<del>CS</del>	Chip select. A conversion process begins on the falling edge of $\overline{\text{CS}}$ .
POWER SUP	PLY	
1	V <sub>DD</sub>	Positive supply pin. These pins should be connected to a quiet +2.7V to +5.25V source and bypassed to GND with 0.1 µF and 1 µF monolithic capacitors located within 1 cm of the power pin. The ADCS7476/77/78 uses this power supply as a reference, so it should be thoroughly bypassed.
2	GND	The ground return for the supply.

### **Block Diagram**





These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

## Absolute Maximum Ratings (1)(2)

Supply Voltage V <sub>DD</sub>	-0.3V to +6.5V
Voltage on Any Analog Pin to GND	-0.3V to V <sub>DD</sub> +0.3V
Voltage on Any Digital Pin to GND	-0.3V to 6.5V
Input Current at Any Pin (3)	±10 mA
ESD Susceptibility Human Body Model Machine Model	3500V 200V
Soldering Temperature, Infrared, 10 seconds	215°C
Junction Temperature	+150°C
Storage Temperature	-65°C to +150°C

- (1) Absolute maximum ratings are limiting values, to be applied individually, and beyond which the serviceability of the circuit may be impaired. Functional operability under any of these conditions is not implied. Exposure to maximum ratings for extended periods may affect device reliability.
- (2) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/ Distributors for availability and specifications.
- (3) Except power supply pins.



www.ti.com

**Operating Ratings** 

Operating Temperature Range	$T_{MIN} = -40^{\circ}C \le T_{A} \le T_{MAX} = +125^{\circ}C$
V <sub>DD</sub> Supply Voltage	+2.7V to +5.25V
Digital Input Pins Voltage Range (1)	+2.7V to +5.25V

<sup>(1)</sup> Independent of supply voltage.

**Package Thermal Resistance** 

Package	θ <sub>JA</sub>
6-Lead SOT-23	265°C / W
6-Lead WSON	78°C / W

# ADCS7476/ADCS7477/ADCS7478 Specifications<sup>(1)</sup> ADCS7476 Converter Electrical Characteristics

The following specifications apply for  $V_{DD}$  = +2.7V to 5.25V,  $f_{SCLK}$  = 20 MHz,  $f_{SAMPLE}$  = 1 MSPS unless otherwise noted. **Boldface limits apply for T<sub>A</sub>** = -40°C to +85°C: all other limits  $T_A$  = 25°C, unless otherwise noted.

Symbol	Parameter	Conditions	Typical	Limits	Units
STATIC	CONVERTER CHARACTERISTICS				
	Resolution with No Missing Codes	V <sub>DD</sub> = 2.7V to 3.6V, -40°C ≤ T <sub>A</sub> ≤ 125°C		12	Bits
INL	Integral New Linearity	$V_{DD} = 2.7V \text{ to } 3.6V,$ -40°C \le T_A \le 85°C	±0.4	±1	LSB (max)
IINL	Integral Non-Linearity	$V_{DD} = 2.7V \text{ to } 3.6V,$ $T_A = 125^{\circ}C$		+1 -1.1	LSB (max) LSB (min)
DNII	Differential New Linearity	$V_{DD} = 2.7V \text{ to } 3.6V,$ -40°C \le T_A \le 85°C	+0.5 -0.3	+1 -0.9	LSB (max) LSB (min)
DNL	Differential Non-Linearity	$V_{DD} = 2.7V \text{ to } 3.6V,$ $T_A = 125^{\circ}C$		±1	LSB (max)
V <sub>OFF</sub>	Offset Error	V <sub>DD</sub> = 2.7V to 3.6V, -40°C ≤ T <sub>A</sub> ≤ 125°C	±0.1	±1.2	LSB (max)
GE	Gain Error	$V_{DD} = 2.7V \text{ to } 3.6V,$ -40°C \le T_A \le 125°C	±0.2	±1.2	LSB (max)
DYNAMI	C CONVERTER CHARACTERISTICS				
SINAD	Signal-to-Noise Plus Distortion Ratio	$f_{IN} = 100 \text{ kHz}, -40^{\circ}\text{C} \le T_{A} \le 125^{\circ}\text{C}$	72	70	dB (min)
SNR	Signal-to-Noise Ratio	$f_{\text{IN}} = 100 \text{ kHz}, -40^{\circ}\text{C} \le T_{\text{A}} \le 85^{\circ}\text{C}$	72.5	70.8	dB (min)
SINK	Signal-to-Noise Ratio	f <sub>IN</sub> = 100 kHz, T <sub>A</sub> = 125°C		70.6	dB (min)
THD	Total Harmonic Distortion	$f_{IN} = 100 \text{ kHz}$	-80		dB
SFDR	Spurious-Free Dynamic Range	f <sub>IN</sub> = 100 kHz	82		dB
IMD	Intermodulation Distortion, Second Order Terms	f <sub>a</sub> = 103.5 kHz, f <sub>b</sub> = 113.5 kHz	-78		dB
טואוט	Intermodulation Distortion, Third Order Terms	f <sub>a</sub> = 103.5 kHz, f <sub>b</sub> = 113.5 kHz	-78		dB
	2 dD Fell Dames Dandmidth	+5V Supply	11		MHz
FPBW	-3 dB Full Power Bandwidth	+3V Supply	8		MHz
POWER	SUPPLY CHARACTERISTICS				
\/	Supply Voltage	-40°C ≤ T <sub>A</sub> ≤ 125°C		2.7	V (min)
$V_{DD}$	Supply voltage	-40 C \( \( \) 1 A \( \) 125 C		5.25	V (max)

<sup>(1)</sup> Data sheet min/max specification limits are ensured by design, test, or statistical analysis.



### ADCS7476/ADCS7477/ADCS7478 Specifications(1) **ADCS7476 Converter Electrical Characteristics (continued)**

The following specifications apply for  $V_{DD}$  = +2.7V to 5.25V,  $f_{SCLK}$  = 20 MHz,  $f_{SAMPLE}$  = 1 MSPS unless otherwise noted. **Boldface limits apply for T<sub>A</sub>** = **-40°C to +85°C**: all other limits T<sub>A</sub> = 25°C, unless otherwise noted.

Symbol	Parameter	Conditions	Typical	Limits	Units
	Normal Mode (Static)	$V_{DD}$ = +4.75V to +5.25V, SCLK On or Off	2		mA
	rioma mode (ciallo)	V <sub>DD</sub> = +2.7V to +3.6V, SCLK On or Off	1		mA
Normal Mode (Star  Normal Mode (Star  Normal Mode (Ope Shutdown Mode  Power Consumptic (Operational)  Input Range  IDCL DC Leakage Curre (OINA Analog Input Capa  DIGITAL INPUT CHARACTE  VIH Input High Voltage  VIL Input Current  CIND Digital Input Capac  DIGITAL OUTPUT CHARACT  VOH Output High Voltage  VOL Output Low Voltage  IOL TRI-STATE Leaka  COUT TRI-STATE Output Output Coding  AC ELECTRICAL CHARACT  fSCLK Clock Frequency  DC SCLK Duty Cycle	Normal Mada (Operational)	$V_{DD}$ = +4.75V to +5.25V, $f_{SAMPLE}$ = 1 MSPS	2.0	3.5	mA (max)
	Normal Mode (Operational)	$V_{DD}$ = +2.7V to +3.6V, $f_{SAMPLE}$ = 1 MSPS	0.6	1.6	mA (max)
	Shutdown Modo	V <sub>DD</sub> = +5V, SCLK Off	0.5	1.6  17.5  4.8  (DD)  ±1  2.4  0.8  0.4  1.6	μA
	Shutdown wode	V <sub>DD</sub> = +5V, SCLK On	60		μA
	Power Consumption, Normal Mode	V <sub>DD</sub> = +5V, f <sub>SAMPLE</sub> = 1 MSPS	10	17.5	mW (max)
PD         (O           Pc         Pc             ANALOG INF           VIN         Inp           IDCL         DC           CINA         Ar	(Operational)	V <sub>DD</sub> = +3V, f <sub>SAMPLE</sub> = 1 MSPS	2	4.8	mW (max)
		V <sub>DD</sub> = +5V, SCLK Off	2.5		μW
	Power Consumption, Shutdown Mode	V <sub>DD</sub> = +3V, SCLK Off	1.5		μW
ANALOG	INPUT CHARACTERISTICS		II.		
V <sub>IN</sub>	Input Range		0 to V <sub>DD</sub>		V
	DC Leakage Current			±1	μA (max)
	Analog Input Capacitance		30		pF
V <sub>IH</sub>	Input High Voltage			2.4	V (min)
		V <sub>DD</sub> = +5V		0.8	V (max)
V <sub>IL</sub>	Input Low Voltage	V <sub>DD</sub> = +3V		0.4	V (max)
I <sub>IN</sub>	Input Current	V <sub>IN</sub> = 0V or V <sub>DD</sub>	±10 nA	±1	μA (max)
	Digital Input Capacitance		2	4	pF (max)
	OUTPUT CHARACTERISTICS		II.		
V <sub>OH</sub>	Output High Voltage	$I_{SOURCE}$ = 200 $\mu$ A, $V_{DD}$ = +2.7V to +5.25V		V <sub>DD</sub> -0.2	V (min)
V <sub>OL</sub>	Output Low Voltage	I <sub>SINK</sub> = 200 μA		0.4	V (max)
	TRI-STATE Leakage Current			±10	μA (max)
C <sub>OUT</sub>	TRI-STATE Output Capacitance		2	4	pF (max)
	Output Coding		Stra	ight (Natural)	) Binary
AC ELEC	TRICAL CHARACTERISTICS				
f <sub>SCLK</sub>	Clock Frequency	-40°C ≤ T <sub>A</sub> ≤ 125°C		20	MHz (max)
DC	SCLK Duty Cycle			40 60	% (min) % (max)
t <sub>TH</sub>	Track/Hold Acquisition Time			400	ns (max)
f <sub>RATE</sub>	Throughput Rate	See USING THE ADCS7476/77/78		1	MSPS (max)
t <sub>AD</sub>	Aperture Delay		3		ns
t <sub>AJ</sub>	Aperture Jitter		30		ps

## ADCS7476/ADCS7477/ADCS7478 Specifications<sup>(1)</sup> ADCS7477 Converter Electrical **Characteristics**

The following specifications apply for  $V_{DD}$  = +2.7V to 5.25V,  $f_{SCLK}$  = 20 MHz,  $f_{SAMPLE}$  = 1 MSPS unless otherwise noted. Boldface limits apply for  $T_A = -40^{\circ}$ C to +85°C: all other limits  $T_A = 25^{\circ}$ C, unless otherwise noted.

Symbol	Parameter	Conditions	Typical	Limits	Units
STATIC C	ONVERTER CHARACTERISTICS				

Data sheet min/max specification limits are ensured by design, test, or statistical analysis.



# ADCS7476/ADCS7477/ADCS7478 Specifications<sup>(1)</sup> ADCS7477 Converter Electrical Characteristics (continued)

The following specifications apply for  $V_{DD}$  = +2.7V to 5.25V,  $f_{SCLK}$  = 20 MHz,  $f_{SAMPLE}$  = 1 MSPS unless otherwise noted. **Boldface limits apply for T<sub>A</sub>** = -40°C to +85°C: all other limits T<sub>A</sub> = 25°C, unless otherwise noted.

Symbol	Parameter	Conditions	Typical	Limits	Units
	Resolution with No Missing Codes			10	Bits
INL	Integral Non-Linearity		±0.2	±0.7	LSB (max)
DNL	Differential Non-Linearity		+0.3 -0.2	±0.7	LSB (max) LSB (min)
V <sub>OFF</sub>	Offset Error		±0.1	±0.7	LSB (max)
GE	Gain Error		±0.2	±1	LSB (max)
DYNAMIC	CONVERTER CHARACTERISTICS				
SINAD	Signal-to-Noise Plus Distortion Ratio	f <sub>IN</sub> = 100 kHz	61.7	61	dBFS (min)
SNR	Signal-to-Noise Ratio	f <sub>IN</sub> = 100 kHz	62		dB
THD	Total Harmonic Distortion	f <sub>IN</sub> = 100 kHz	-77	-73	dB (max)
SFDR	Spurious-Free Dynamic Range	f <sub>IN</sub> = 100 kHz	78	74	dB (min)
IMD	Intermodulation Distortion, Second Order Terms	$f_a = 103.5 \text{ kHz}, f_b = 113.5 \text{ kHz}$	-78		dB
NIL	Intermodulation Distortion, Third Order Terms	$f_a = 103.5 \text{ kHz}, f_b = 113.5 \text{ kHz}$	-78		dB
EDR\//	-3 dB Full Power Bandwidth	+5V Supply	11	10 ±0.7 ±0.7 ±0.7 ±1 61	MHz
FFDVV	-3 dB Full Fower Balldwidth	+3V Supply	8		MHz
POWER S	SUPPLY CHARACTERISTICS				
$V_{DD}$	Supply Voltage				V (min) V (max)
I <sub>DD</sub>	Normal Mode (Static)	$V_{DD}$ = +4.75V to +5.25V, SCLK On or Off	2		mA
		$V_{DD}$ = +2.7V to +3.6V, SCLK On or Off	1		mA
	Normal Mode (Operational)	$V_{DD} = +4.75V \text{ to } +5.25V,$ $f_{SAMPLE} = 1 \text{ MSPS}$	2.0	3.5	mA (max)
		$V_{DD}$ = +2.7V to +3.6V, $f_{SAMPLE}$ = 1 MSPS	0.6	1.6	mA (max)
	Shutdown Mode	V <sub>DD</sub> = +5V, SCLK Off	0.5	10 ±0.7 ±0.7 ±0.7 ±1 61 -73 74 2.7 5.25 3.5 1.6 17.5 4.8 ±1 4	μA (max)
	Shutdown Mode	V <sub>DD</sub> = +5V, SCLK On	60		μA (max)
	Power Consumption, Normal Mode	V <sub>DD</sub> = +5V, f <sub>SAMPLE</sub> = 1 MSPS	10	10 ±0.7 ±0.7 ±1 61 -73 74 2.7 5.25 3.5 1.6 17.5 4.8 ±1 4	mW (max)
D_	(Operational)	$V_{DD} = +3V$ , $f_{SAMPLE} = 1$ MSPS	2	4.8	mW (max)
ט י	Power Consumption, Shutdown Mode	V <sub>DD</sub> = +5V, SCLK Off	2.5		μW (max)
	r ower consumption, chataewii wode	V <sub>DD</sub> = +3V, SCLK Off	1.5	10 2 ±0.7 3 2 ±0.7 1 ±0.7 2 ±1 7 61 7 -73 74 8 8 8 9 1.6 9 1.6 9 1.7.5 4.8 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1.6 9 1	μW (max)
ANALOG	INPUT CHARACTERISTICS				
$V_{IN}$	Input Range		0 to V <sub>DD</sub>		V
I <sub>DCL</sub>	DC Leakage Current			±1	μA (max)
	Analog Input Capacitance		30		pF
DIGITAL	INPUT CHARACTERISTICS				
V <sub>IH</sub>	Input High Voltage			2.4	V (min)
$V_{IL}$	Input Low Voltage	V <sub>DD</sub> = +5V		0.8	V (max)
* IL	input zow voltage	V <sub>DD</sub> = +3V		0.4	V (max)
I <sub>IN</sub>	Input Current	$V_{IN} = 0V \text{ or } V_{DD}$	±10 nA	±1	μA (max)
C <sub>IND</sub>	Digital Input Capacitance		2	4	pF (max)
DIGITAL	OUTPUT CHARACTERISTICS				
V <sub>OH</sub>	Output High Voltage	I <sub>SOURCE</sub> = 200 μA, V <sub>DD</sub> = +2.7V to +5.25V		V <sub>DD</sub> -0.2	V (min)



# ADCS7476/ADCS7477/ADCS7478 Specifications<sup>(1)</sup> ADCS7477 Converter Electrical Characteristics (continued)

The following specifications apply for  $V_{DD}$  = +2.7V to 5.25V,  $f_{SCLK}$  = 20 MHz,  $f_{SAMPLE}$  = 1 MSPS unless otherwise noted. **Boldface limits apply for T<sub>A</sub>** = -40°C to +85°C: all other limits T<sub>A</sub> = 25°C, unless otherwise noted.

Symbol	Parameter	Conditions	Typical	Limits	Units
V <sub>OL</sub>	Output Low Voltage	I <sub>SINK</sub> = 200 μA		0.4	V (max)
I <sub>OL</sub>	TRI-STATE Leakage Current			±10	μA (max)
C <sub>OUT</sub>	TRI-STATE Output Capacitance		2	4	pF (max)
	Output Coding		Stra	ight (Natural	) Binary
AC ELEC	TRICAL CHARACTERISTICS				
f <sub>SCLK</sub>	Clock Frequency			20	MHz (max)
DC	SCLK Duty Cycle			40 60	% (min) % (max)
t <sub>TH</sub>	Track/Hold Acquisition Time			400	ns (max)
f <sub>RATE</sub>	Throughput Rate	See USING THE ADCS7476/77/78		1	MSPS (max)
t <sub>AD</sub>	Aperture Delay		3		ns
t <sub>AJ</sub>	Aperture Jitter		30		ps





# ADCS7476/ADCS7477/ADCS7478 Specifications<sup>(1)</sup> ADCS7478 Converter Electrical Characteristics

The following specifications apply for  $V_{DD} = +2.7V$  to 5.25V,  $f_{SCLK} = 20$  MHz,  $f_{SAMPLE} = 1$  MSPS unless otherwise noted. **Boldface limits apply for T<sub>A</sub> = -40°C to +85°C**: all other limits  $T_A = 25$ °C, unless otherwise noted.

Symbol	Parameter	Conditions	Typical	Limits	Units
STATIC	CONVERTER CHARACTERISTICS				
	Resolution with No Missing Codes			8	Bits
INL	Integral Non-Linearity		±0.05	±0.3	LSB (max)
DNL	Differential Non-Linearity		±0.07	±0.3	LSB (max)
V <sub>OFF</sub>	Offset Error		±0.03	±0.3	LSB (max)
GE	Gain Error		±0.08	±0.4	LSB (max)
	Total Unadjusted Error		±0.07	±0.3	LSB (max)
DYNAMI	C CONVERTER CHARACTERISTICS				*
SINAD	Signal-to-Noise Plus Distortion Ratio	f <sub>IN</sub> = 100 kHz	49.7	49	dB (min)
SNR	Signal-to-Noise Ratio	f <sub>IN</sub> = 100 kHz	49.7		dB
THD	Total Harmonic Distortion	f <sub>IN</sub> = 100 kHz	-77	-65	dB (max)
SFDR	Spurious-Free Dynamic Range	f <sub>IN</sub> = 100 kHz	69	65	dB (min)
IMD	Intermodulation Distortion, Second Order Terms	f <sub>a</sub> = 103.5 kHz, f <sub>b</sub> = 113.5 kHz	-68		dB
IMD	Intermodulation Distortion, Third Order Terms	f <sub>a</sub> = 103.5 kHz, f <sub>b</sub> = 113.5 kHz	-68		dB
EDDIM	O dD Fell Decree Decrete date	+5V Supply	11		MHz
FPBW	-3 dB Full Power Bandwidth	+3V Supply	8		MHz
POWER	SUPPLY CHARACTERISTICS		,		
$V_{DD}$	Supply Voltage			2.7 5.25	V (min) V (max)
	Normal Mode (Static)	V <sub>DD</sub> = +4.75V to +5.25V, SCLK On or Off	2		mA
		$V_{DD}$ = +2.7V to +3.6V, SCLK On or Off	1		mA
I <sub>DD</sub>	Normal Mode (Operational)	$V_{DD} = +4.75V \text{ to } +5.25V,$ $f_{SAMPLE} = 1 \text{ MSPS}$	2.0	3.5	mA (max)
		$V_{DD}$ = +2.7V to +3.6V, $f_{SAMPLE}$ = 1 MSPS	0.6	1.6	mA (max)
	Chutdour Mada	V <sub>DD</sub> = +5V, SCLK Off	0.5		μA (max)
	Shutdown Mode	V <sub>DD</sub> = +5V, SCLK On	60		μA (max)
	Power Consumption, Normal Mode	V <sub>DD</sub> = +5V, f <sub>SAMPLE</sub> = 1 MSPS	10	17.5	mW (max)
Б	(Operational)	V <sub>DD</sub> = +3V, f <sub>SAMPLE</sub> = 1 MSPS	2	4.8	mW (max)
$P_D$	Device Consumation Chatdown Made	V <sub>DD</sub> = +5V, SCLK Off	2.5		μW (max)
	Power Consumption= Shutdown Mode	V <sub>DD</sub> = +3V, SCLK Off	1.5		μW (max)
ANALOG	INPUT CHARACTERISTICS				•
V <sub>IN</sub>	Input Range		0 to V <sub>DD</sub>		V
I <sub>DCL</sub>	DC Leakage Current			±1	μA (max)
C <sub>INA</sub>	Analog Input Capacitance		30		pF
DIGITAL	INPUT CHARACTERISTICS	*	,		
$V_{IH}$	Input High Voltage			2.4	V (min)
V	Input Low Voltage	$V_{DD} = +5V$		0.8	V (max)
V <sub>IL</sub>	Input Low Voltage	$V_{DD} = +3V$		0.4	V (max)
. —	Digital Input Current	$V_{IN} = 0V \text{ or } V_{DD}$	±10 nA	±1	μA (max)
I <sub>IN</sub>	Digital Input Current	VIN - OV OI VDD	210101		pri (max)

<sup>(1)</sup> Data sheet min/max specification limits are ensured by design, test, or statistical analysis.

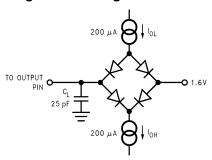


# ADCS7476/ADCS7477/ADCS7478 Specifications<sup>(1)</sup> ADCS7478 Converter Electrical Characteristics (continued)

The following specifications apply for  $V_{DD}$  = +2.7V to 5.25V,  $f_{SCLK}$  = 20 MHz,  $f_{SAMPLE}$  = 1 MSPS unless otherwise noted. **Boldface limits apply for T<sub>A</sub>** = -40°C to +85°C: all other limits T<sub>A</sub> = 25°C, unless otherwise noted.

Symbol	Parameter	Conditions	Typical	Limits	Units
V <sub>OH</sub>	Output High Voltage	$I_{SOURCE} = 200 \mu A,$ $V_{DD} = +2.7V \text{ to } +5.25V$		V <sub>DD</sub> -0.2	V (min)
$V_{OL}$	Output Low Voltage	I <sub>SINK</sub> = 200 μA		0.4	V (max)
I <sub>OL</sub>	TRI-STATE Leakage Current			±10	μA (max)
C <sub>OUT</sub>	TRI-STATE Output Capacitance		2	4	pF (max)
	Output Coding		Stra	aight (Natural)	Binary
AC ELEC	TRICAL CHARACTERISTICS				
f <sub>SCLK</sub>	Clock Frequency			20	MHz (max)
DC	SCLK Duty Cycle			40 60	% (min) % (max)
t <sub>TH</sub>	Track/Hold Acquisition Time			400	ns (max)
f <sub>RATE</sub>	Throughput Rate	See Applications Information		1	MSPS (min)
t <sub>AD</sub>	Aperture Delay		3		ns
t <sub>AJ</sub>	Aperture Jitter		30		ps

Figure 2. Timing Test Circuit



## Timing Test Circuit ADCS7476/ADCS7477/ADCS7478 Timing Specifications

The following specifications apply for  $V_{DD}$  = +2.7V to 5.25V,  $f_{SCLK}$  = 20 MHz, **Boldface limits apply for T<sub>A</sub>** = **-40°C to +85°C**: all other limits  $T_A$  = 25°C, unless otherwise noted. (1)

Symbol	Parameter	Conditions	Typical	Limits	Units
t <sub>CONVERT</sub>			16 x t <sub>SCLK</sub>		
t <sub>QUIET</sub>	(2)			50	ns (min)
t <sub>1</sub>	Minimum CS Pulse Width			10	ns (min)
t <sub>2</sub>	CS to SCLK Setup Time			10	ns (min)
t <sub>3</sub>	Delay from CS Until SDATA TRI-STATE Disabled (3)			20	ns (max)
	Data Access Time after SCLK Falling	V <sub>DD</sub> = +2.7 to +3.6		40	ns (max)
t <sub>4</sub>	Edge <sup>(4)</sup>	$V_{DD} = +4.75 \text{ to } +5.25$		20	ns (max)
t <sub>5</sub>	SCLK Low Pulse Width			0.4 x t <sub>SCLK</sub>	ns (min)
t <sub>6</sub>	SCLK High Pulse Width			0.4 x t <sub>SCLK</sub>	ns (min)
	CCLV to Data Valid Hold Time	$V_{DD} = +2.7 \text{ to } +3.6$		7	ns (min)
t <sub>7</sub>	SCLK to Data Valid Hold Time	V <sub>DD</sub> = +4.75 to +5.25		5	ns (min)

- (1) All input signals are specified as  $t_r = t_f = 5$  ns (10% to 90%  $V_{DD}$ ) and timed from 1.6V.
- (2) Minimum Quiet Time Required Between Bus Relinquish and Start of Next Conversion
- (3) Measured with the load circuit shown above, and defined as the time taken by the output to cross 1.0V.
- (4) Measured with the load circuit shown above, and defined as the time taken by the output to cross 1.0V or 2.0V.



## Timing Test Circuit ADCS7476/ADCS7477/ADCS7478 Timing Specifications (continued)

The following specifications apply for  $V_{DD}$  = +2.7V to 5.25V,  $f_{SCLK}$  = 20 MHz, **Boldface limits apply for T<sub>A</sub>** = -40°C to +85°C: all other limits T<sub>A</sub> = 25°C, unless otherwise noted. (1)

Symbol	Parameter	Conditions	Typical	Limits	Units
t <sub>8</sub>		V .0.745 .0.0		25	ns (max)
	SCLK Falling Edge to SDATA High	$V_{DD} = +2.7 \text{ to } +3.6$		6	ns (min)
	SCLK Falling Edge to SDATA High Impedance <sup>(5)</sup>	V . 4.75 to .5.05	25	ns (max)	
		$V_{DD} = +4.75 \text{ to } +5.25$		5	ns (min)
t <sub>POWER</sub> -	Power-Up Time from Full Power-Down		1		μs

<sup>(5)</sup> t<sub>8</sub> is derived from the time taken by the outputs to change by 0.5V with the loading circuit shown above. The measured number is then adjusted to remove the effects of charging or discharging the 25pF capacitor. This means t<sub>8</sub> is the true bus relinquish time, independent of the bus loading.

#### **Specification Definitions**

- **APERTURE DELAY** is the variation in aperture delay from sample to sample. Aperture jitter manifests itself as noise in the output.
- **APERTURE JITTER (APERTURE UNCERTAINTY)** is the variation in aperture delay from sample to sample. Aperture jitter manifests itself as noise in the output.
- **DIFFERENTIAL NON-LINEARITY (DNL)** is the measure of the maximum deviation from the ideal step size of 1 LSB.
- **DUTY CYCLE** is the ratio of the time that a repetitive digital waveform is high to the total time of one period. The specification here refers to the SCLK.
- **EFFECTIVE NUMBER OF BITS (ENOB, or EFFECTIVE BITS)** is another method of specifying Signal-to-Noise and Distortion or SINAD. ENOB is defined as (SINAD 1.76) / 6.02 and says that the converter is equivalent to a perfect ADC of this (ENOB) number of bits.
- **FULL POWER BANDWIDTH** is a measure of the frequency at which the reconstructed output fundamental drops 3 dB below its low frequency value for a full scale input.
- **GAIN ERROR** is the deviation of the last code transition (111...110) to (111...111) from the ideal ( $V_{REF}$  1.5 LSB for ADCS7476 and ADCS7477,  $V_{REF}$  1 LSB for ADCS7478), after adjusting for offset error.
- INTEGRAL NON-LINEARITY (INL) is a measure of the deviation of each individual code from a line drawn from negative full scale (½ LSB below the first code transition) through positive full scale (½ LSB above the last code transition). The deviation of any given code from this straight line is measured from the center of that code value.
- **INTERMODULATION DISTORTION (IMD)** is the creation of additional spectral components as a result of two sinusoidal frequencies being applied to the ADC input at the same time. It is defined as the ratio of the power in the either the two second order or all four third order intermodulation products to the sum of the power in both of the original frequencies. IMD is usually expressed in dBFS.
- **MISSING CODES** are those output codes that will never appear at the ADC outputs. The ADCS7476/77/78 is ensured not to have any missing codes.
- **OFFSET ERROR** is the deviation of the first code transition (000...000) to (000...001) from the ideal (i.e. GND + 0.5 LSB for the ADCS7476 and ADCS7477, and GND + 1 LSB for the ADCS7478).
- **SIGNAL TO NOISE RATIO (SNR)** is the ratio, expressed in dB, of the rms value of the input signal to the rms value of the sum of all other spectral components below one-half the sampling frequency, not including harmonics or DC.
- **SIGNAL TO NOISE PLUS DISTORTION (S/N+D or SINAD)** Is the ratio, expressed in dB, of the rms value of the input signal to the rms value of all of the other spectral components below half the clock frequency, including harmonics but excluding DC.
- **SPURIOUS FREE DYNAMIC RANGE (SFDR)** is the difference, expressed in dB, between the rms values of the input signal and the peak spurious signal, where a spurious signal is any signal present in the output

(1)



spectrum that is not present at the input.

**TOTAL HARMONIC DISTORTION (THD)** is the ratio, expressed in dBc, of the rms total of the first five harmonic levels at the output to the level of the fundamental at the output. THD is calculated as

THD = 20 x log 
$$\sqrt{\frac{f_2^2 + \dots + f_6^2}{f_1^2}}$$

where

- f<sub>1</sub> is the RMS power of the fundamental (output) frequency
- f<sub>2</sub> through f<sub>6</sub> are the RMS power in the first 5 harmonic frequencies

**TOTAL UNADJUSTED ERROR** is the worst deviation found from the ideal transfer function. As such, it is a comprehensive specification which includes full scale error, linearity error, and offset error.

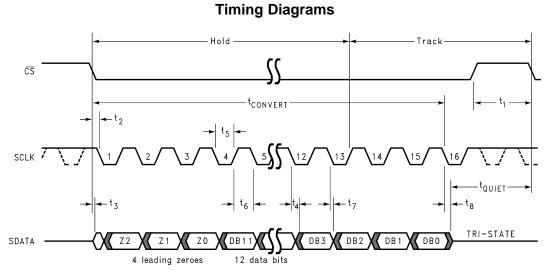


Figure 3. ADCS7476 Serial Interface Timing Diagram

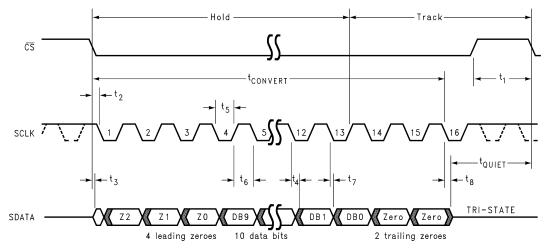


Figure 4. ADCS7477 Serial Interface Timing Diagram



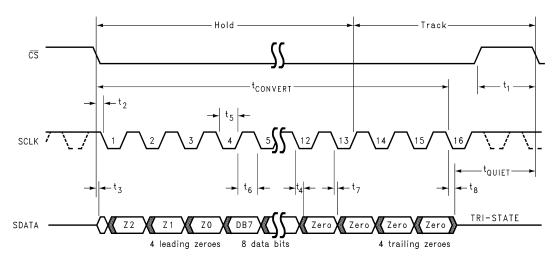
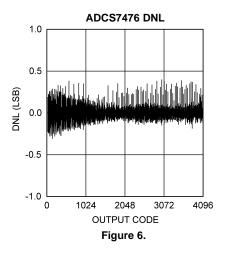


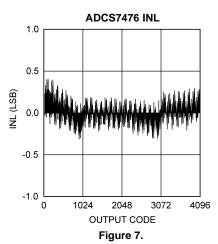
Figure 5. ADCS7478 Serial Interface Timing Diagram



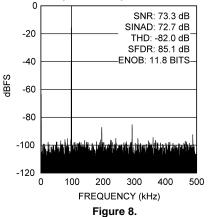
### **Typical Performance Characteristics**

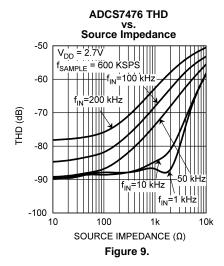
 $T_A = +25$ °C,  $V_{DD} = 3V$ ,  $f_{SAMPLE} = 1$  MSPS,  $f_{SCLK} = 20$  MHz,  $f_{IN} = 100$  kHz unless otherwise stated. **ADCS7476** 



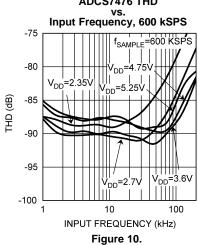


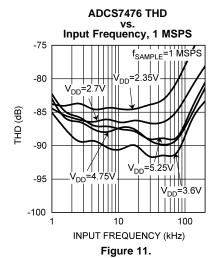
#### ADCS7476 Spectral Response @ 100kHz Input





#### ADCS7476 THD



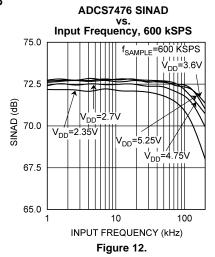


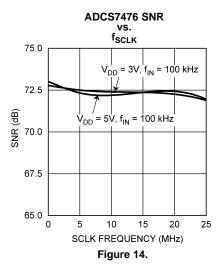


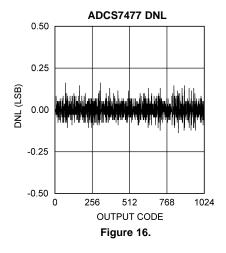
## **Typical Performance Characteristics (continued)**

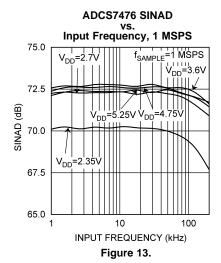
 $T_A = +25$ °C,  $V_{DD} = 3V$ ,  $f_{SAMPLE} = 1$  MSPS,  $f_{SCLK} = 20$  MHz,  $f_{IN} = 100$  kHz unless otherwise stated.

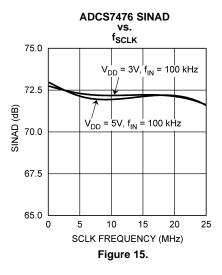
#### **ADCS7476**

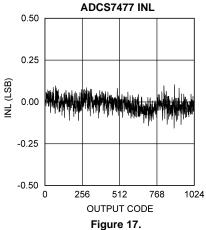














## **Typical Performance Characteristics (continued)**

 $T_A$  = +25°C,  $V_{DD}$  = 3V,  $f_{SAMPLE}$  = 1 MSPS,  $f_{SCLK}$  = 20 MHz,  $f_{IN}$  = 100 kHz unless otherwise stated.

#### **ADCS7476**



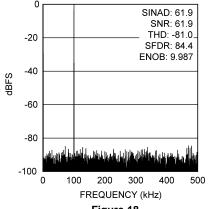
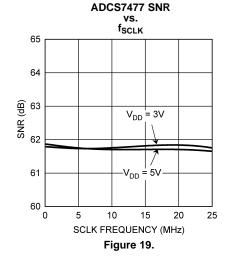


Figure 18.





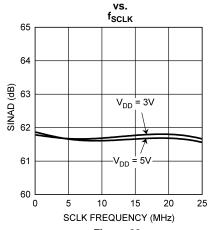
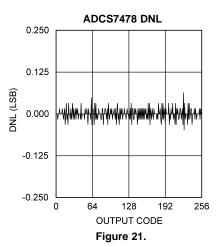
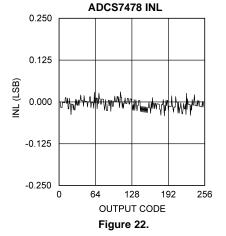
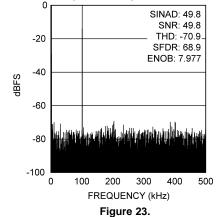


Figure 20.



ADCS7478 Spectral Response @ 100kHz Input



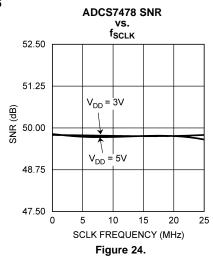


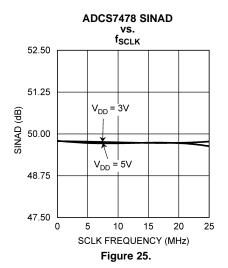


## **Typical Performance Characteristics (continued)**

 $T_A = +25$ °C,  $V_{DD} = 3V$ ,  $f_{SAMPLE} = 1$  MSPS,  $f_{SCLK} = 20$  MHz,  $f_{IN} = 100$  kHz unless otherwise stated.

#### **ADCS7476**







#### **APPLICATIONS INFORMATION**

#### ADCS7476/77/78 OPERATION

The ADCS7476/77/78 are successive-approximation analog-to-digital converters designed around a charge-redistribution digital-to-analog converter. Simplified schematics of the ADCS7476/77/78 in both track and hold operation are shown in Figure 26 and Figure 27, respectively. In Figure 26 the device is in track mode: switch SW1 connects the sampling capacitor to the input, and SW2 balances the comparator inputs. The device is in this state until  $\overline{CS}$  is brought low, at which point the device moves to hold mode.

Figure 27 shows the device in hold mode: switch SW1 connects the sampling capacitor to ground, maintaining the sampled voltage, and switch SW2 unbalances the comparator. The control logic then instructs the charge-redistribution DAC to add or subtract fixed amounts of charge from the sampling capacitor until the comparator is balanced. When the comparator is balanced, the digital word supplied to the DAC is the digital representation of the analog input voltage. The device moves from hold mode to track mode on the 13th rising edge of SCLK.

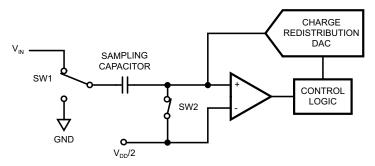


Figure 26. ADCS7476/77/78 in Track Mode

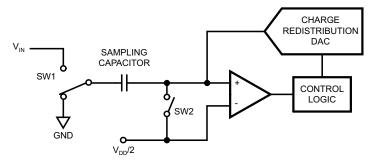


Figure 27. ADCS7476/77/78 in Hold Mode

#### **USING THE ADCS7476/77/78**

Serial interface timing diagrams for the ADCS7476/77/78 are shown in Figure 3, Figure 4, and Figure 5.  $\overline{\text{CS}}$  is chip select, which initiates conversions and frames the serial data transfers. SCLK (serial clock) controls both the conversion process and the timing of serial data. SDATA is the serial data out pin, where a conversion result is found.

Basic operation of the ADCS7476/77/78 begins with  $\overline{\text{CS}}$  going low, which initiates a conversion process and data transfer. Subsequent rising and falling edges of SCLK will be labeled with reference to the <u>falling</u> edge of  $\overline{\text{CS}}$ ; for example, "the third falling edge of SCLK" shall refer to the third falling edge of SCLK after  $\overline{\text{CS}}$  goes low.

At the fall of  $\overline{\text{CS}}$ , the SDATA pin comes out of TRI-STATE, and the converter moves from track mode to hold mode. The input signal is sampled and held for conversion at the falling edge of  $\overline{\text{CS}}$ . The converter moves from hold mode to track mode on the 13th rising edge of SCLK (see Figure 3, Figure 4, or Figure 5). The SDATA pin will be placed back into TRI-STATE after the 16th falling edge of SCLK, or at the rising edge of  $\overline{\text{CS}}$ , whichever occurs first. After a conversion is completed, the quiet time  $t_{\text{QUIET}}$  must be satisfied before bringing  $\overline{\text{CS}}$  low again to begin another conversion.



Sixteen SCLK cycles are required to read a complete sample from the ADCS7476/77/78. The sample bits (including any leading or trailing zeroes) are clocked out on falling edges of SCLK, and are intended to be clocked in by a receiver on subsequent falling edges of SCLK. The ADCS7476/77/78 will produce four leading zeroes on SDATA, followed by twelve, ten, or eight data bits, most significant first. After the data bits, the ADCS7477 will clock out two trailing zeros, and the ADCS7478 will clock out four trailing zeros. The ADCS7476 will not clock out any trailing zeros; the least significant data bit will be valid on the 16th falling edge of SCLK.

Depending upon the application, the first edge on SCLK after  $\overline{\text{CS}}$  goes low may be either a falling edge or a rising edge. If the first SCLK edge after  $\overline{\text{CS}}$  goes low is a rising edge, all four leading zeroes will be valid on the first four falling edges of SCLK. If instead the first SCLK edge after  $\overline{\text{CS}}$  goes low is a falling edge, the first leading zero may not be set up in time for a microprocessor or DSP to read it correctly. The remaining data bits are still clocked out on the falling edges of SCLK.

#### ADCS7476/77/78 TRANSFER FUNCTION

The output format of the ADCS7476/77/78 is straight binary. Code transitions occur midway between successive integer LSB values. The LSB widths for the ADCS7476 is  $V_{DD}$  / 4096; for the ADCS7477 the LSB width is  $V_{DD}$  / 1024; for the ADCS7478, the LSB width is  $V_{DD}$  / 256. The ideal transfer characteristic for the ADCS7476 and ADCS7477 is shown in Figure 28, while the ideal transfer characteristic for the ADCS7478 is shown in Figure 29.

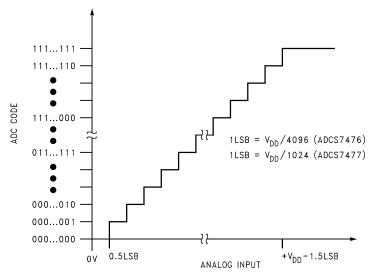


Figure 28. ADCS7476/77 Ideal Transfer Characteristic

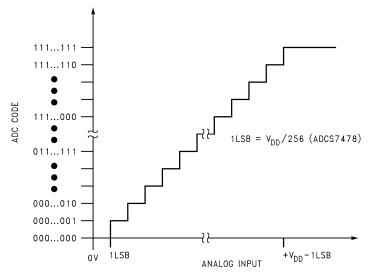


Figure 29. ADCS7478 Ideal Transfer Characteristic



#### TYPICAL APPLICATION CIRCUIT

A typical application of the ADCS7476/77/78 is shown in Figure 30. The combined analog and digital supplies are provided in this example by the TI LP2950 low-dropout voltage regulator, available in a variety of fixed and adjustable output voltages. The supply is bypassed with a capacitor network located close to the device. The three-wire interface is also shown connected to a microprocessor or DSP.

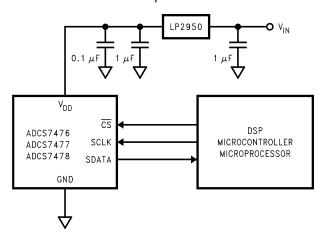


Figure 30. Typical Application Circuit

#### **ANALOG INPUTS**

An equivalent circuit for the ADCS7476/77/78 input channel is shown in Figure 31. The diodes D1 and D2 provide ESD protection for the analog inputs. At no time should an analog input exceed  $V_{DD}$  + 300 mV or GND - 300 mV, as these ESD diodes will begin conducting current into the substrate or supply line and affect ADC operation.

The capacitor C1 in Figure 31 typically has a value of 4 pF, and is mainly due to pin capacitance. The resistor R1 represents the on resistance of the multiplexer and track / hold switch, and is typically 100 ohms. The capacitor C2 is the ADCS7476/77/78 sampling capacitor, and is typically 26 pF.

The sampling nature of the analog input causes input current pulses that result in voltage spikes at the input. The ADCS7476/77/78 will deliver best performance when driven by a low-impedance source to eliminate distortion caused by the charging of the sampling capacitance. In applications where dynamic performance is critical, the input might need to be driven with a low output-impedance amplifier. In addition, when using the ADCS7476/77/78 to sample AC signals, a band-pass or low-pass filter will reduce harmonics and noise and thus improve THD and SNR.

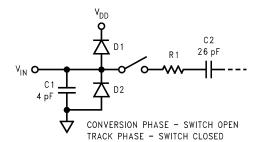


Figure 31. Equivalent Input Circuit

### **DIGITAL INPUTS AND OUTPUTS**

The ADCS7476/77/78 digital inputs (SCLK and  $\overline{\text{CS}}$ ) are not limited by the same absolute maximum ratings as the analog inputs. The digital input pins are instead limited to +6.5V with respect to GND, regardless of V<sub>DD</sub>, the supply voltage. This allows the ADCS7476/77/78 to be interfaced with a wide range of logic levels, independent of the supply voltage.

Submit Documentation Feedback



Note that, even though the digital inputs are tolerant of up to +6.5V above GND, the digital outputs are only capable of driving  $V_{DD}$  out. In addition, the digital input pins are not prone to latch-up; SCLK and  $\overline{CS}$  may be asserted before  $V_{DD}$  without any risk.

#### MODES OF OPERATION

The ADCS7476/77/78 has two possible modes of operation: NORMAL MODE, and SHUTDOWN MODE. The ADCS7476/77/78 enters normal mode (and a conversion process is begun) when  $\overline{CS}$  is pulled low. The device will enter shutdown mode if  $\overline{CS}$  is pulled high before the tenth falling edge of SCLK after  $\overline{CS}$  is pulled low, or will stay in normal mode if  $\overline{CS}$  remains low. Once in shutdown mode, the device will stay there until  $\overline{CS}$  is brought low again. By varying the ratio of time spent in the normal and shutdown modes, a system may trade-off throughput for power consumption.

#### NORMAL MODE

The best possible throughput is obtained by leaving the ADCS7476/77/78 in normal mode at all times, so there are no power-up delays. To keep the device in normal mode continuously,  $\overline{\text{CS}}$  must be kept low until after the 10th falling edge of SCLK after the start of a conversion (remember that a conversion is initiated by bringing  $\overline{\text{CS}}$  low).

If  $\overline{\text{CS}}$  is brought high after the 10th falling edge, but before the 16th falling edge, the device will remain in normal mode, but the current conversion will be aborted, and SDATA will return to TRI-STATE (truncating the output word).

Sixteen SCLK cycles are required to read all of a conversion word from the device. After sixteen SCLK cycles have elapsed,  $\overline{CS}$  may be idled either high or low until the next conversion. If  $\overline{CS}$  is idled low, it must be brought high again before the start of the next conversion, which begins when  $\overline{CS}$  is again brought low.

After sixteen SCLK cycles, SDATA returns to TRI-STATE. Another conversion may be started, after  $t_{QUIET}$  has elapsed, by bringing  $\overline{CS}$  low again.

#### **SHUTDOWN MODE**

Shutdown mode is appropriate for applications that either do not sample continuously, or are willing to trade throughput for power consumption. When the ADCS7476/77/78 is in shutdown mode, all of the analog circuitry is turned off.

To enter shutdown mode, a conversion must be interrupted by bringing  $\overline{CS}$  back high anytime between the second and tenth falling edges of SCLK, as shown in Figure 32. Once  $\overline{CS}$  has been brought high in this manner, the device will enter shutdown mode; the current conversion will be aborted and SDATA will enter TRI-STATE. If  $\overline{CS}$  is brought high before the second falling edge of  $\underline{SCLK}$ , the device will not change mode; this is to avoid accidentally changing mode as a result of noise on the  $\overline{CS}$  line.

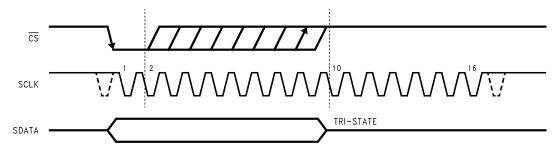


Figure 32. Entering Shutdown Mode



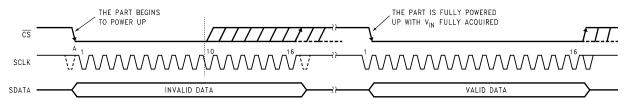


Figure 33. Entering Normal Mode

#### **EXITING SHUTDOWN MODE**

To exit shutdown mode, bring  $\overline{CS}$  back low. Upon bringing  $\overline{CS}$  low, the ADCS7476/77/78 will begin powering up. Power up typically takes 1 µs. This microsecond of power-up delay results in the first conversion result being unusable. The second conversion performed after power-up, however, is valid, as shown in Figure 33.

If CS is brought back high before the 10th falling edge of SCLK, the device will return to shutdown mode. This is done to avoid accidentally entering normal mode as a result of noise on the CS line. To exit shutdown mode and remain in normal mode, CS must be kept low until after the 10th falling edge of SCLK. The ADCS7476/77/78 will be fully powered-up after 16 SCLK cycles.

#### **POWER-UP TIMING**

The ADCS7476/77/78 typically requires 1  $\mu$ s to power up, either after first applying V<sub>DD</sub>, or after returning to normal mode from shutdown mode. This corresponds to one "dummy" conversion for any SCLK frequency within the specifications in this document. After this first dummy conversion, the ADCS7476/77/78 will perform conversions properly. Note that the toulet time must still be included between the first dummy conversion and the second valid conversion.

#### **STARTUP MODE**

When the V<sub>DD</sub> supply is first applied, the ADCS7476/77/78 may power up in either of the two modes: normal or shutdown. As such, one dummy conversion should be performed after start-up, exactly as described in POWER-UP TIMING. The part may then be placed into either normal mode or the shutdown mode, as described in NORMAL MODE and SHUTDOWN MODE.

#### **POWER CONSIDERATIONS**

There are three concerns relating to the power supply of these products: the effects of Power Supply Noise upon the conversion process, the Digital Output Effect Upon Noise upon the conversion process and Power Management of the product.

#### **Power Supply Noise**

Since the reference voltage of the ADCS7476/77/78 is the reference voltage, any noise greater than 1/2 LSB in amplitude will have some effect upon the converter noise performance. This effect is proportional to the input voltage level. The power supply should receive all the considerations of a reference voltage as far as stability and noise is concerned. Using the same supply voltage for these devices as is used for digital components will lead to degraded noise performance.

#### **Digital Output Effect Upon Noise**

The charging of any output load capacitance requires current from the digital supply, V<sub>DD</sub>. The current pulses required from the supply to charge the output capacitance will cause voltage variations at the ADC supply line. If these variations are large enough, they could degrade SNR and SINAD performance of the ADC. Similarly, discharging the output capacitance when the digital output goes from a logic high to a logic low will dump current into the die substrate, causing "ground bounce" noise in the substrate that will degrade noise performance if that current is large enough. The larger the output capacitance, the more current flows through the device power supply line and die substrate and the greater is the noise coupled into the analog path.

Submit Documentation Feedback



The first solution to keeping digital noise out of the power supply is to decouple the supply from any other components or use a separate supply for the ADC. To keep noise out of the supply, keep the output load capacitance as small as practical. If the load capacitance is greater than 50 pF, use a 100  $\Omega$  series resistor at the ADC output, located as close to the ADC output pin as practical. This will limit the charge and discharge current of the output capacitance and improve noise performance. Since the series resistor and the load capacitance form a low frequency pole, verify signal integrity once the series resistor has been added.

#### **Power Management**

When the ADCS7476/77/78 is operated continuously in normal mode, throughput up to 1 MSPS can be achieved. The user may trade throughput for power consumption by simply performing fewer conversions per unit time, and putting the ADCS7476/77/78 into shutdown mode between conversions. This method is not advantageous beyond 350 kSPS throughput.

A plot of maximum power consumption versus throughput is shown in Figure 34. To calculate the power consumption for a given throughput, remember that each time the part exits shutdown mode and enters normal mode, one dummy conversion is required. Generally, the user will put the part into normal mode, execute one dummy conversion followed by one valid conversion, and then put the part back into shutdown mode. When this is done, the fraction of time spent in normal mode may be calculated by multiplying the throughput (in samples per second) by  $2~\mu s$ , the time taken to perform one dummy and one valid conversion. The power consumption can then be found by multiplying the fraction of time spent in normal mode by the normal mode power consumption figure. The power dissipated while the part is in shutdown mode is negligible.

For example, to calculate the power consumption at 300 kSPS with  $V_{DD}$  = 5V, begin by calculating the fraction of time spent in normal mode: 300,000 samples/second x 2  $\mu$ s = 0.6, or 60%. The power consumption at 300 kSPS is then 60% of 17.5 mW (the maximum power consumption at  $V_{DD}$  = 5V) or 10.5 mW.

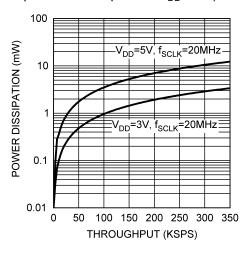


Figure 34. Maximum Power Consumption vs. Throughput

### LAYOUT AND GROUNDING

Capacitive coupling between noisy digital circuitry and sensitive analog circuitry can lead to poor performance. The solution is to keep the analog and digital circuitry separated from each other and the clock line as short as possible.

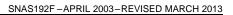
Digital circuits create substantial supply and ground current transients. This digital noise could have significant impact upon system noise performance. To avoid performance degradation of the ADCS7476/77/78 due to supply noise, do not use the same supply for the ADCS7476/77/78 that is used for digital logic.

Generally, analog and digital lines should cross each other at 90° to avoid crosstalk. However, to maximize accuracy in high resolution systems, avoid crossing analog and digital lines altogether. It is important to keep clock lines as short as possible and isolated from ALL other lines, including other digital lines. In addition, the clock line should also be treated as a transmission line and be properly terminated.



The analog input should be isolated from noisy signal lines to avoid coupling of spurious signals into the input. Any external component (e.g., a filter capacitor) connected between the converter's input pins and ground or to the reference input pin and ground should be connected to a very clean point in the ground plane.

We recommend the use of a single, uniform ground plane and the use of split power planes. The power planes should be located within the same board layer. All analog circuitry (input amplifiers, filters, reference components, etc.) should be placed over the analog power plane. All digital circuitry and I/O lines should be placed over the digital power plane. Furthermore, all components in the reference circuitry and the input signal chain that are connected to ground should be connected together with short traces and enter the analog ground plane at a single, quiet point.





NSTRUMENTS

## **REVISION HISTORY**

Cł	nanges from Revision E (March 2013) to Revision F	Pag	ge
•	Changed layout of National Data Sheet to TI format	:	22





25-Mar-2013

#### **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
ADCS7476AIMF	ACTIVE	SOT-23	DBV	6	1000	TBD	Call TI	Call TI	-40 to 125	X01A	Samples
ADCS7476AIMF/NOPB	ACTIVE	SOT-23	DBV	6	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	X01A	Samples
ADCS7476AIMFE/NOPB	ACTIVE	SOT-23	DBV	6	250	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	X01A	Samples
ADCS7476AIMFX	ACTIVE	SOT-23	DBV	6	3000	TBD	Call TI	Call TI	-40 to 125	X01A	Samples
ADCS7476AIMFX/NOPB	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	X01A	Samples
ADCS7477AIMF	ACTIVE	SOT-23	DBV	6	1000	TBD	Call TI	Call TI	-40 to 85	X02A	Samples
ADCS7477AIMF/NOPB	ACTIVE	SOT-23	DBV	6	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	X02A	Samples
ADCS7477AIMFE/NOPB	ACTIVE	SOT-23	DBV	6	250	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	X02A	Samples
ADCS7477AIMFX	ACTIVE	SOT-23	DBV	6	3000	TBD	Call TI	Call TI	-40 to 85	X02A	Samples
ADCS7477AIMFX/NOPB	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	X02A	Samples
ADCS7478AIMF	ACTIVE	SOT-23	DBV	6	1000	TBD	Call TI	Call TI	-40 to 85	X03A	Samples
ADCS7478AIMF/NOPB	ACTIVE	SOT-23	DBV	6	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	X03A	Samples
ADCS7478AIMFE/NOPB	ACTIVE	SOT-23	DBV	6	250	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	X03A	Samples
ADCS7478AIMFX	ACTIVE	SOT-23	DBV	6	3000	TBD	Call TI	Call TI	-40 to 85	X03A	Samples
ADCS7478AIMFX/NOPB	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	X03A	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.



## PACKAGE OPTION ADDENDUM

25-Mar-2013

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

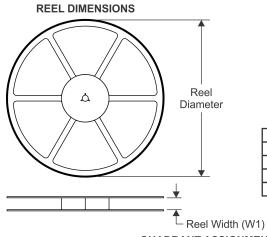
**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

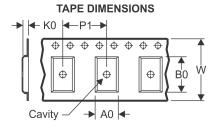
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

## PACKAGE MATERIALS INFORMATION

www.ti.com 26-Mar-2013

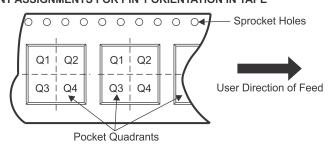
## TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

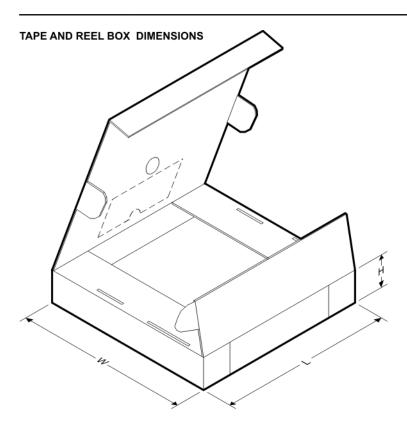
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
ADCS7476AIMF	SOT-23	DBV	6	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
ADCS7476AIMF/NOPB	SOT-23	DBV	6	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
ADCS7476AIMFE/NOPB	SOT-23	DBV	6	250	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
ADCS7476AIMFX	SOT-23	DBV	6	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
ADCS7476AIMFX/NOPB	SOT-23	DBV	6	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
ADCS7477AIMF	SOT-23	DBV	6	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
ADCS7477AIMF/NOPB	SOT-23	DBV	6	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
ADCS7477AIMFE/NOPB	SOT-23	DBV	6	250	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
ADCS7477AIMFX	SOT-23	DBV	6	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
ADCS7477AIMFX/NOPB	SOT-23	DBV	6	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
ADCS7478AIMF	SOT-23	DBV	6	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
ADCS7478AIMF/NOPB	SOT-23	DBV	6	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
ADCS7478AIMFE/NOPB	SOT-23	DBV	6	250	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
ADCS7478AIMFX	SOT-23	DBV	6	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
ADCS7478AIMFX/NOPB	SOT-23	DBV	6	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3

www.ti.com 26-Mar-2013

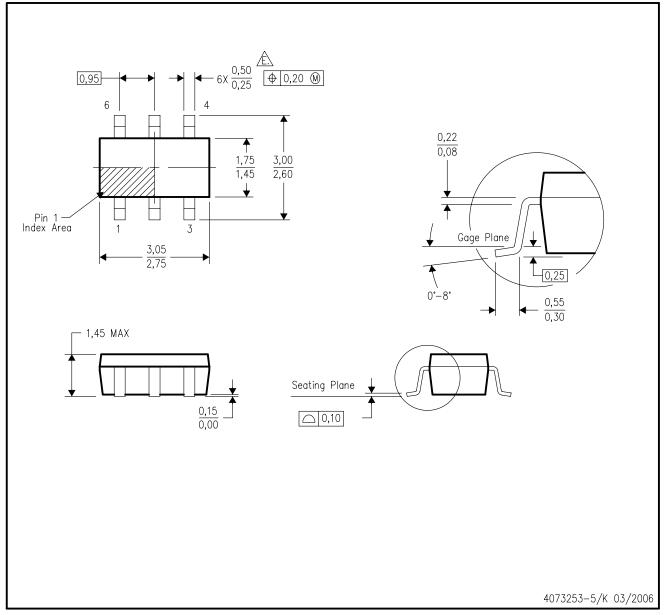


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
ADCS7476AIMF	SOT-23	DBV	6	1000	210.0	185.0	35.0
ADCS7476AIMF/NOPB	SOT-23	DBV	6	1000	210.0	185.0	35.0
ADCS7476AIMFE/NOPB	SOT-23	DBV	6	250	210.0	185.0	35.0
ADCS7476AIMFX	SOT-23	DBV	6	3000	210.0	185.0	35.0
ADCS7476AIMFX/NOPB	SOT-23	DBV	6	3000	210.0	185.0	35.0
ADCS7477AIMF	SOT-23	DBV	6	1000	210.0	185.0	35.0
ADCS7477AIMF/NOPB	SOT-23	DBV	6	1000	210.0	185.0	35.0
ADCS7477AIMFE/NOPB	SOT-23	DBV	6	250	210.0	185.0	35.0
ADCS7477AIMFX	SOT-23	DBV	6	3000	210.0	185.0	35.0
ADCS7477AIMFX/NOPB	SOT-23	DBV	6	3000	210.0	185.0	35.0
ADCS7478AIMF	SOT-23	DBV	6	1000	210.0	185.0	35.0
ADCS7478AIMF/NOPB	SOT-23	DBV	6	1000	210.0	185.0	35.0
ADCS7478AIMFE/NOPB	SOT-23	DBV	6	250	210.0	185.0	35.0
ADCS7478AIMFX	SOT-23	DBV	6	3000	210.0	185.0	35.0
ADCS7478AIMFX/NOPB	SOT-23	DBV	6	3000	210.0	185.0	35.0

# DBV (R-PDSO-G6)

## PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
- Falls within JEDEC MO-178 Variation AB, except minimum lead width.



#### IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have *not* been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products Applications

Audio www.ti.com/audio Automotive and Transportation www.ti.com/automotive Communications and Telecom **Amplifiers** amplifier.ti.com www.ti.com/communications **Data Converters** dataconverter.ti.com Computers and Peripherals www.ti.com/computers **DLP® Products** www.dlp.com Consumer Electronics www.ti.com/consumer-apps

DSP **Energy and Lighting** dsp.ti.com www.ti.com/energy Clocks and Timers www.ti.com/clocks Industrial www.ti.com/industrial Interface interface.ti.com Medical www.ti.com/medical logic.ti.com Logic Security www.ti.com/security

Power Mgmt power.ti.com Space, Avionics and Defense www.ti.com/space-avionics-defense

Microcontrollers <u>microcontroller.ti.com</u> Video and Imaging <u>www.ti.com/video</u>

RFID www.ti-rfid.com

OMAP Applications Processors <a href="www.ti.com/omap">www.ti.com/omap</a> TI E2E Community <a href="e2e.ti.com">e2e.ti.com</a>

Wireless Connectivity <u>www.ti.com/wirelessconnectivity</u>



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

#### Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов:
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001:
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



#### Как с нами связаться

**Телефон:** 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина,

дом 2, корпус 4, литера А.